2SC2396, 2SC2543, 2SC2544

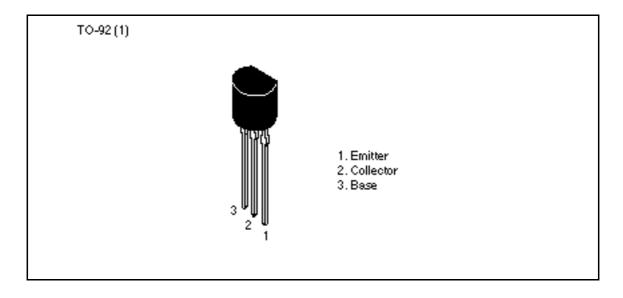
Silicon NPN Epitaxial

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Application

- Low frequency amplifier
- Complementary pair with 2SA1025, 2SA1081 and 2SA1082

Outline





2SC2396, 2SC2543, 2SC2544

Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	2SC2396	2SC2543	2SC2544	Unit
Collector to base voltage	V _{CBO}	60	90	120	V
Collector to emitter voltage	V _{CEO}	60	90	120	V
Emitter to base voltage	V_{EBO}	5	5	5	V
Collector current	I _c	100	100	100	mA
Emitter current	I _E	-100	-100	-100	mA
Collector power dissipation	P _c	400	400	400	mW
Junction temperature	Tj	150	150	150	°C
Storage temperature	Tstg	-55 to +150	-55 to +150	-55 to +150	°C

Electrical Characteristics ($Ta = 25^{\circ}C$)

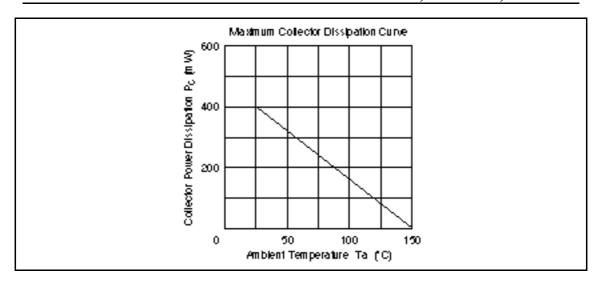
		2SC2	2396		2SC2543		2SC2544					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V _{(BR)CBO}	60	_	_	90	_	_	120	_	_	V	$I_{C} = 10 \ \mu\text{A}, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	60	_	_	90	_	_	120	_	_	V	$I_C = 1 \text{ mA},$ $R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	5	_	_	5	_	_	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I _{CBO}	_	_	0.1	_	_	0.1	_	_	0.1	μΑ	$V_{CB} = 50 \text{ V}, I_{E} = 0$
Emitter cutoff current	I _{EBO}	_	_	0.1	_	_	0.1	_	_	0.1	μΑ	$V_{EB} = 2 \text{ V}, I_{C} = 0$
DC current transfer ratio	h _{FE} *1	250	_	1200	250	_	1200	250	_	800		$V_{CE} = 12 \text{ V},$ $I_{C} = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	_	0.2	_	_	0.2	_	_	0.2	V	$I_C = 10 \text{ mA},$ $I_B = 1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	0.6	_	_	0.6	_	_	0.6	_	V	$V_{CE} = 12 \text{ V},$ $I_{C} = 2 \text{ mA}$
Gain bandwidth product	f _T	_	90	_	_	90	_	_	90	_	MHz	$V_{CE} = 12 \text{ V},$ $I_{C} = 2 \text{ mA}$
Collector output capacitance	Cob	_	3.0	_	_	3.0	_	_	3.0	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0,$ f = 1 MHz

Note: 1. The 2SC2396, 2SC2543 and 2SC2544 are grouped by h_{FE1} as follows.

	D	E	F
2SC2396, 2SC2543	250 to 500	400 to 800	600 to 1200
2SC2544	250 to 500	400 to 800	_

See characteristic curves of 2SC2545, 2SC2546 and 2SC2547.

2SC2396, 2SC2543, 2SC2544



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HITACHI

Hitachi, Ltd.
Semiconductor & IC Div.
Nippon Bidg., 2-6-2, Ohte-medii, Chiyode-ku, Tokyo 100, Jepen Tet Tokyo (03, 3270-2414
Fex: (03, 3270-5109)

For further in formellion write to: Hitechi Americe, Ltd. Semiconductor & IC Dw. 2000 Sierre Point Perkwey Briebene, CA. 94005-4835 U.S.A.

USA Tet 415-589-8300 Fex 415-583-4207 Hitschi Burope GmbH
Bectronic Components Group
Continental Burope
Dornacher Straße 3
D-85822 Feldkirchen
München
Tet 089-9 94 80-0
Fex: 089-9 29 30 00

Hischi Burope Ltd.
Bedronic Components Dv.
Northern Burope Hesidquerters
Whitebrook Ferk
Lower Cook ham Road
Maidenheed
Berkshire SL68YA
Urited Kingdom
Tet 0628-885000
Fex 0628-778222

Hitschi Asia Pte. Ltd 45 Collyer Quey \$20-00 Hitschi Tower Snappore 0104 Tet 535-2100 Fex: 535-1533

Hitachi Asia (Hong Kong) Ltd. Unit 705, North Towar, World Finance Centre, Herbour City, Certon Road Taim She Taul, Kowloon Hong Kong Tet 27:350218 Fax: 27:30607 f